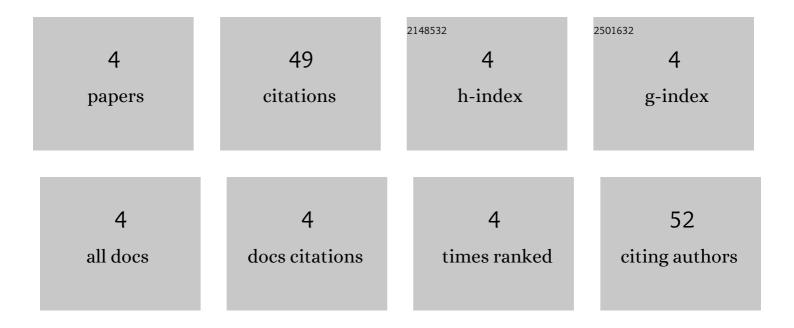
Anli Yang

List of Publications by Year in descending order

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| # | Article | IF | CITATIONS |
|---|---|-----|-----------|
| 1 | Carrier lifetime control by intentional boron doping in aluminum doped p-type 4H-SiC epilayers. Journal of Applied Physics, 2021, 129, . | 1.1 | 6 |
| 2 | Analysis of carrier lifetimes in N + B-doped <i>n</i> -type 4H-SiC epilayers. Journal of Applied Physics, 2019, 126, . | 1.1 | 15 |
| 3 | Wide-ranging control of carrier lifetimes in n-type 4H-SiC epilayer by intentional vanadium doping. Journal of Applied Physics, 2019, 126, . | 1.1 | 21 |
| 4 | Time-resolved photoluminescence spectral analysis of phonon-assisted DAP and e-A recombination in N+B-doped n-type 4H-SiC epilayers. Journal Physics D: Applied Physics, 2019, 52, 10LT01. | 1.3 | 7 |